

Maximum Ratings and Thermal Characteristics (T_A=25°C unless otherwise noted)

	-	0/415.01			
PARAMETE	SYMBOL	LIMIT	UNITS		
Drain-Source Voltage		V _{DS}	150	V	
Gate-Source Voltage		V _{GS}	±20		
Continuous Drain Current ^(Note 3)	Tc=25°C	- I _D -	40		
	$T_{C}=100^{\circ}C$		29	А	
Pulsed Drain Current ^(Note 1)	Tc=25°C	I _{DM}	110		
Power Dissipation	Tc=25°C	D	100	w	
	T _c =100°C	Po	50		
Continuous Drain Current ^(Note 4)	T _A =25°C	I _D	7	A	
	T _A =70 [°] C		6		
Power Dissipation	T _A =25 [°] C	Po -	3	w	
	T _A =70 [°] C		2.1		
Single Pulse Avalanche Current ^(Note 5)		las	9.8	А	
Single Pulse Avalanche Energy ^(Note 5)		Eas	9	mJ	
Operating Junction and Storage Temperature Range		T _J ,T _{STG}	-55~175	°C	
Thermal Resistance ^(Note 4)	Junction to Case	$R_{ extsf{ heta}JC}$	1.5	°C/W	
	Junction to Ambient	R _{0JA}	50		



PJD45N15S-AU

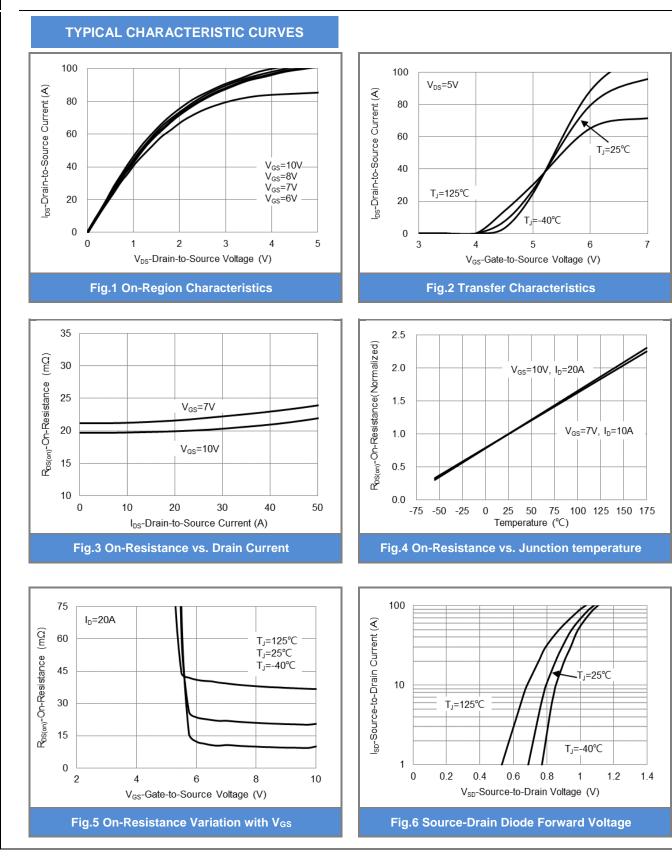
Electrical Characteristics (TA=25°C unless otherwise noted)

PARAMETER	SYMBOL	TEST CONDITION	MIN.	TYP.	MAX.	UNITS	
Static						•	
Drain-Source Breakdown Voltage	BV _{DSS}	V _{GS} =0V, I _D =250uA	150	-	-	V	
Gate Threshold Voltage	V _{GS(th)}	$V_{DS}=V_{GS}$, $I_{D}=250$ uA	2	3	4		
Drain-Source On-State Resistance	R _{DS(on)}	V_{GS} =10V, I_{D} =20A	-	19.6	25		
		V _{GS} =7V, I _D =10A	- 21 2		28	mΩ	
Zero Gate Voltage Drain Current	I _{DSS}	V _{DS} =150V, V _{GS} =0V	-	-	1	uA	
Gate-Source Leakage Current	I _{GSS}	V _{GS} =±20V, V _{DS} =0V	-	-	±100	nA	
Dynamic ^(Note 6)							
Total Gate Charge	Qg		-	36	47	nC	
Gate-Source Charge	Qgs	$V_{DS}=75V, I_{D}=20A,$	-	13	-		
Gate-Drain Charge	Q _{gd}	V _{GS} =10V	-	8	-		
Input Capacitance	Ciss		-	2118	2753	pF	
Output Capacitance	Coss	V _{DS} =75V, V _{GS} =0V, f=1MHz	-	150	225		
Reverse Transfer Capacitance	Crss		-	10	-		
Gate resistance	Rg	f=1MHz	-	0.9	-	Ω	
Turn-On Delay Time	td _(on)		-	12	-		
Turn-On Rise Time	tr	V _{DS} =75V, I _D =20A,	-	31	-	ns	
Turn-Off Delay Time	td(off)	$V_{GS}=10V, R_G=3\Omega$	-	24	-		
Turn-Off Fall Time	tf		-	31	-		
Drain-Source Diode							
Diode Forward Current	I _S	T 05°0	-	-	40	A	
Pulsed Diode Forward Current	I _{SM}	T _c =25°C	-	-	110		
Diode Forward Voltage	V _{SD}	I _S =20A, V _{GS} =0V	-	0.85	1.3	V	
Reverse Recovery Time	Trr	V _{DD} =75V,V _{GS} =0V	-	90	-	ns	
Reverse Recovery Charge	Qrr	Is=20A,dIs/dt=100A/us	-	220	-	nC	

NOTES :

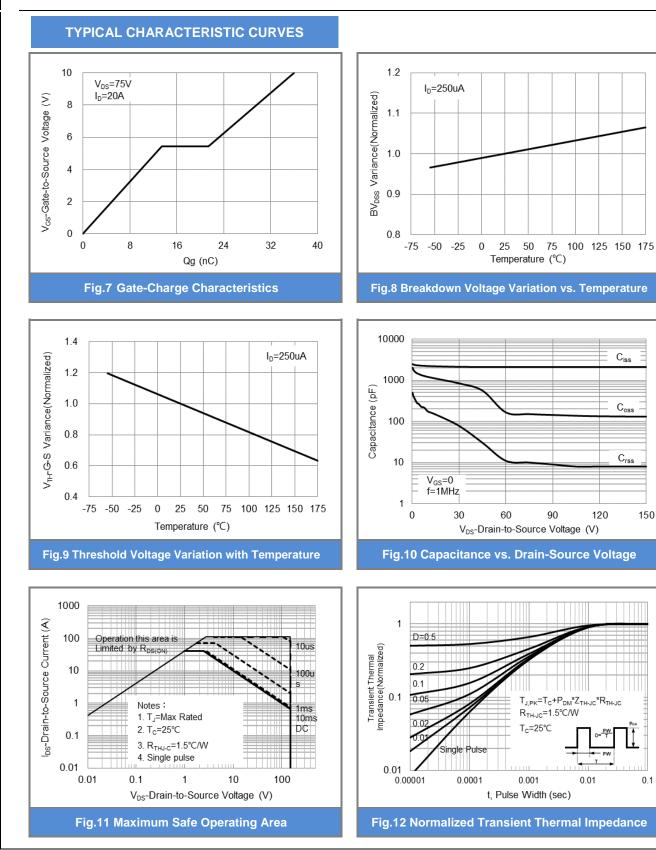
- 1. Pulse width<100us, Duty cycle<2%.
- 2. Essentially independent of operating temperature typical characteristics.
- 3. Chip capability with an $R_{\rm \theta JC}{=}1.5^{\circ}C/W.$
- 4. $R_{\theta JA}$ is the sum of the junction-to-case and case-to-ambient thermal resistance where the case thermal reference is defined as the solder mounting surface of the drain pins. Mounted on a 1 inch² with 2oz.square pad of copper.
- 5. E_{AS} is calculated based on the condition of L=1mH, I_{AS}=4.2A, V_{DD}=30V, V_{GS}=10V. 100% test at L=0.1mH, I_{AS}=9.8A in production.
- 6. Guaranteed by design, not subject to production testing.

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SEM CONDUCTOR

PJD45N15S-AU



150

0.1

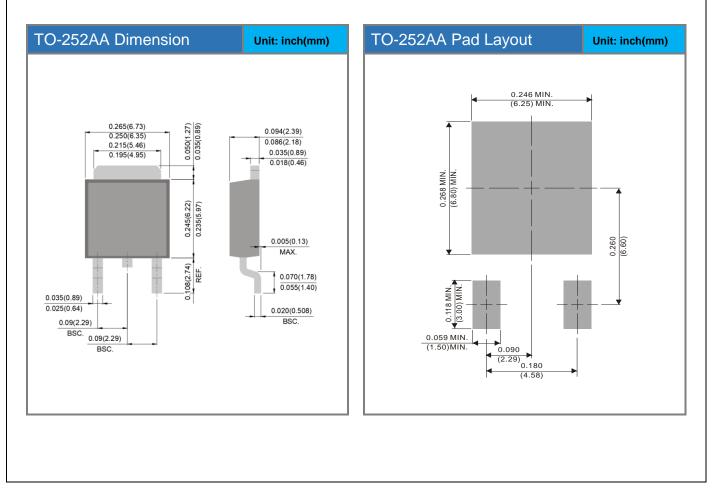


PJD45N15S-AU

Product and Packing Information

Part No.	Package Type	Packing Type	Marking	
PJD45N15S-AU	TO-252AA	3K pcs / 13" reel	D45N15S	

Packaging Information & Mounting Pad Layout





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